

DESCRIPTION

The PC827H optically coupled isolator consist of an infrared light emitting diode and an NPN silicon photo transistor in a space efficient Dual In Line Plastic Package.

FEATURES

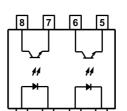
- AC Isolation Voltage 5300V_{RMS}
- CTR Selections Available
- Wide Operating Temperature Range -30°C to +100°C
- Lead Free and RoHS Compliant
- UL File E91231 Package Code "EE"

APPLICATIONS

- Computer Terminals
- Industrial System Controllers
- Measuring Instruments
- Signal Transmission between Systems of Different Potentials and Impedances

ORDER INFORMATION

- Add G after PN for 10mm lead spacing
- Add SM after PN for Surface Mount
- Add SMT&R after PN for Surface Mount Tape & Reel



- 1, 3 Anode
- 2, 4 Cathode
- 5, 7 Emitter
- 6, 8 Collector

ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device.

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Input

Forward Current	50mA
Peak Forward Current (100µs, 100Hz)	1A
Reverse Voltage	6V
Power dissipation	70mW

Output

Collector to Emitter Voltage V _{CEO}	35V
•	
Emitter to Collector Voltage V _{ECO}	6V
Collector Current	50mA
Power Dissipation	150mW

Total Package

Isolation Voltage	$5300V_{RMS}$
Total Power Dissipation	200mW
Operating Temperature	-30 to 100 °C
Junction Temperature	125 °C
Storage Temperature	-55 to 125 °C
Lead Soldering Temperature (10s)	260°C

ISOCOM COMPONENTS 2004 LTD

Unit 25B, Park View Road West, Park View Industrial Estate Hartlepool, Cleveland, TS25 1PE, United Kingdom Tel: +44 (0)1429 863 609 Fax: +44 (0)1429 863 581 e-mail: sales@isocom.co.uk

http://www.isocom.com

ISOCOM COMPONENTS ASIA LTD

Hong Kong Office
Block A, 8/F, Wah Hing Industrial Mansion
36 Tai Yau Street, San Po Kong, Kowloon, Hong Kong
Tel: +852 2995 9217 Fax: +852 8161 6292
e-mail: sales@isocom.com.hk



ELECTRICAL CHARACTERISTICS (Ambient Temperature = 25°C unless otherwise specified)

INPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	$V_{\rm F}$	$I_F = 20 \text{mA}$		1.2	1.4	V
Reverse Leakage	I_R	$V_R = 4V$			10	μΑ
Terminal Capacitance	C_{t}	V = 0V, $f = 1KHz$		30	250	pF

OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	BV _{CEO}	$I_C = 0.1 \text{mA}, I_F = 0 \text{mA}$	35			V
Emitter-Collector Breakdown Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E=10\mu A,I_F=0mA$	6			V
Collector-Emitter Dark Current	I_{CEO}	$V_{CE} = 20V$, $I_F = 0mA$			100	nA



ELECTRICAL CHARACTERISTICS (Ambient Temperature = 25°C unless otherwise specified)

COUPLED

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	CTR	$I_F = 5mA$, $V_{CE} = 5V$	50		600	%
		Optional CTR Grades GB BL GR A B C D	100 200 100 80 130 200 300		600 600 300 160 260 400 600	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_F = 20 \text{mA}, I_C = 1 \text{mA}$		0.1	0.2	V
Floating Capacitance	C_{f}	V = 0V, $f = 1MHz$		0.6	1	pF
Cut-Off Frequency	fc	$V_{CE} = 5V$, $I_C = 2mA$, $R_L = 100\Omega$, $-3dB$		80		kHz
Output Rise Time	$t_{\rm r}$	$V_{CE} = 2V$, Ic = 2mA,		4	18	μs
Output Fall Time	t_{f}	$R_L = 100\Omega$		3	18	

ISOLATION

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Input to Output Isolation Voltage	$V_{\rm ISO}$	AC 1 minute, RH = 40% to 60% Note 1	5300			V_{RMS}
Input to Output Isolation Resistance	$R_{\rm ISO}$	V_{IO} = 500V, RH = 40% to 60% Note 1	5x10 ¹⁰	1x10 ¹¹		Ω

Note 1: Measure with input leads shorted together and output leads shorted together.



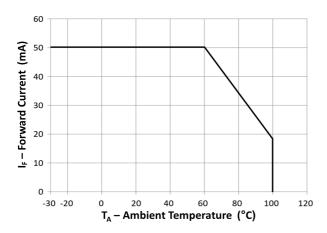


Fig 1 Forward Current vs Ambient Temperature

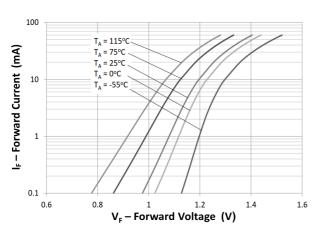


Fig 3 Forward Current vs Forward Voltage

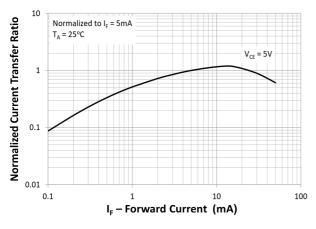


Fig 5 Normalized Current Transfer Ratio vs Forward Current

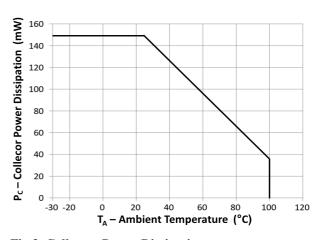


Fig 2 Collector Power Dissipation vs Ambient Temperature

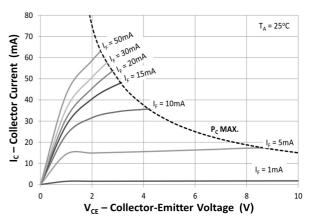


Fig 4 Collector Current vs Collector-Emitter Voltage

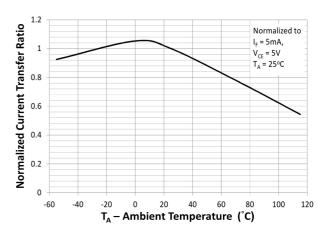


Fig 6 Normalized Current Transfer Ratio vs Ambient Temperature



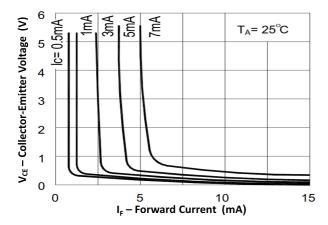


Fig 7 Collector-Emitter Voltage vs Forward Current

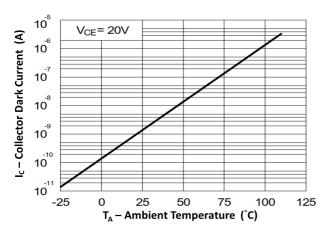


Fig 9 Collector Dark Current vs Ambient Temperature

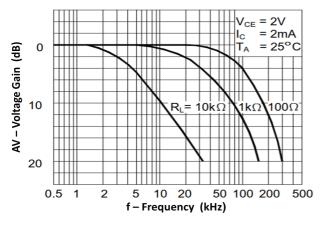


Fig 11 Frequency Response

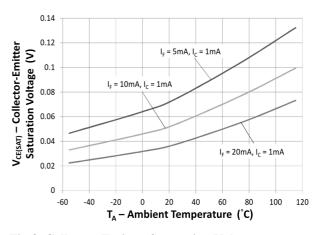


Fig 8 Collector-Emitter Saturation Voltage vs Ambient Temperature

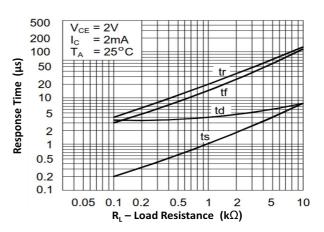
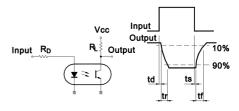
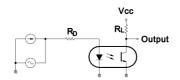


Fig 10 Response Time vs Load Resistance



Response Time Test Circuit



Frequency Response Test Circuit



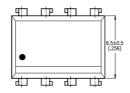
ORDER INFORMATION

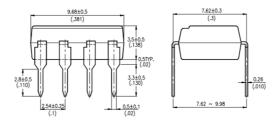
	PC827H (UL Approval)							
After PN	PN Description		Packing Quantity					
None	PC827H, PC827HGB, PC827HBL, PC827HGR, PC827HA, PC827HB, PC827HC, PC827HD	Standard DIP8	50 pcs per tube					
G	PC827HG, PC827HGBG, PC827HBLG, PC827HGRG, PC827HAG, PC827HBG, PC827HCG, PC827HDG	10mm Lead Spacing	50 pcs per tube					
SM	PC827HSM, PC827HGBSM, PC827HBLSM, PC827GRSM, PC827HASM, PC827HBSM, PC827HCSM, PC827HDSM	Surface Mount	50 pcs per tube					
SMT&R	PC827HSMT&R, PC827HGBSMT&R, PC827HGRSMT&R, PC827HBLSMT&R, PC827HASMT&R, PC827HCSMT&R, PC827HCSMT&R	Surface Mount Tape & Reel	1000 pcs per reel					



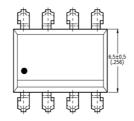
PACKAGE DIMENSIONS in mm (inch)

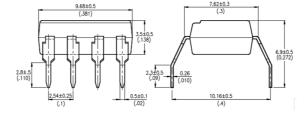




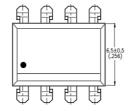


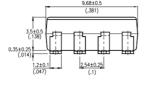
PC827HG

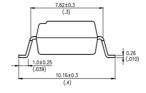




PC827HSM

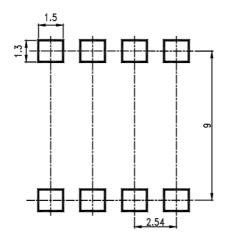




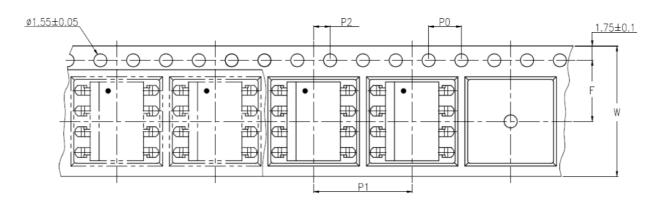


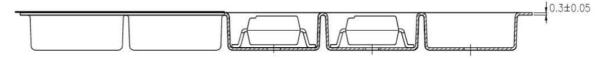


RECOMMENDED PAD LAYOUT FOR SMD (mm)



TAPE AND REEL PACKAGING

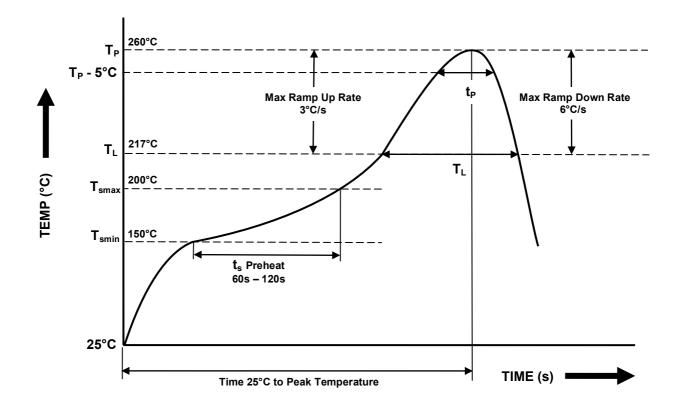




Description	Symbol	Dimension mm (inch)
Tape Width	W	16 ± 0.3 (0.63)
Pitch of Sprocket Holes	P ₀	4 ± 0.1 (0.15)
Distance of Compartment to Sprocket Holes	F	7.5 ± 0.1 (0.295)
Distance of Compartment to Sprocket Holes	P ₂	2 ± 0.1 (0.079)
Distance of Compartment to Compartment	P ₁	12 ± 0.1 (0.472)



IR REFLOW SOLDERING TEMPERATURE PROFILE FOR SMD One Time Reflow Soldering is Recommended. Do not immerse device body in solder paste.



Profile Details	Conditions
Preheat - Min Temperature (T _{SMIN}) - Max Temperature (T _{SMAX}) - Time T _{SMIN} to T _{SMAX} (t _s)	150°C 200°C 60s - 120s
$\begin{tabular}{ll} \textbf{Soldering Zone} \\ - & \begin{tabular}{ll} - & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} - & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{T}_P & \begin{tabular}{ll} \textbf{S}^\circ \textbf{C} & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{T}_P & \begin{tabular}{ll} \textbf{S}^\circ \textbf{C} & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{T}_P & \begin{tabular}{ll} \textbf{S}^\circ \textbf{C} & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{T}_P & \begin{tabular}{ll} \textbf{S}^\circ \textbf{C} & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{T}_P & \begin{tabular}{ll} \textbf{S}^\circ \textbf{C} & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{T}_P & \begin{tabular}{ll} \textbf{Peak Temperature } & \begin{tabular}{ll} \textbf{T}_P & \begin{tabular}{ll$	260°C 10s max 217°C 30s max 60s - 100s 3°C/s max 6°C/s max
Average Ramp Up Rate (T _{smax} to T _P)	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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